KSC2785YTA Datasheet

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DiGi Electronics Part Number	KSC2785YTA-DG
Manufacturer	onsemi
Manufacturer Product Number	KSC2785YTA
Description	TRANS NPN 50V 0.15A TO92S
Detailed Description	Bipolar (BJT) Transistor NPN 50 V 150 mA 300MHz 250 mW Through Hole TO-92S

Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
KSC2785YTA	onsemi
Series:	Product Status:
-	Obsolete
Transistor Type:	Current - Collector (Ic) (Max):
NPN	150 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ Ib, Ic:
50 V	300mV @ 10mA, 100mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
100nA (ICBO)	120 @ 1mA, 6V
Power - Max:	Frequency - Transition:
250 mW	300MHz
Operating Temperature:	Mounting Type:
150°C (TJ)	Through Hole
Package / Case:	Supplier Device Package:
TO-226-3, TO-92-3 Short Body	TO-92S
Base Product Number:	
KSC2785	

Environmental & Export classification

Moisture Sensitivity Level (MSL):	REACH Status:
1 (Unlimited)	REACH Unaffected
ECCN:	HTSUS:
EAR99	8541.21.0075

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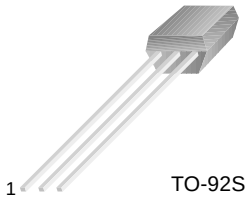
KSC2785

Audio Frequency Amplifier & High Frequency OSC.

- Complement to KSA1175
- Collector-Base Voltage : V_{CBO}=60V



TO-92S

1.Emitter 2. Collector 3. Base

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	60	V
V_{CEO}	Collector-Emitter Voltage	50	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current	150	mA
P_C	Collector Power Dissipation	250	mW
T_J	Junction Temperature	150	°C
T_{STG}	Storage Temperature	-55 ~ 150	°C

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
BV_{CBO}	Collector-Base Breakdown Voltage	I_C=100μA, I_E=0	60			V
BV_{CEO}	Collector-Emitter Breakdown Voltage	I_C=10mA, I_B=0	50			V
BV_{EBO}	Emitter-Base Breakdown Voltage	I_E=10μA, I_C=0	5			V
I_{CBO}	Collector Cut-off Current	V_{CB}=40V, I_E=0			0.1	μA
I_{EBO}	Emitter Cut-off Current	V_{EB}=3V, I_C=0			0.1	μA
h_{FE}	DC Current Gain	V_{CE}=6V, I_C=1.0mA	70		700	
V_{CE} (sat)	Collector-Emitter Saturation Voltage	I_C=100mA, I_B=10mA		0.15	0.3	V
f_T	Current Gain Bandwidth Product	V_{CE}=6V, I_C=10mA		300		MHz
C_{ob}	Output Capacitance	V_{CB}=6V, I_E=0, f=1MHz		2.5		pF
NF	Noise Figure	V_{CE}=6, I_C=0.5mA f=1KHz, R_S=500Ω		4.0		dB

h_{FE} Classification

Classification	O	Y	G	L
h_{FE}	70 ~ 140	120 ~ 240	200 ~ 400	350 ~ 700

Typical Characteristics

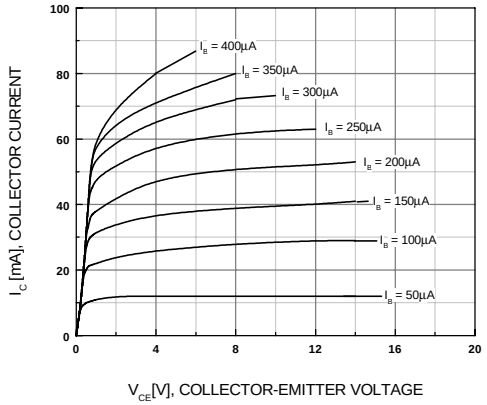


Figure 1. Static Characteristics

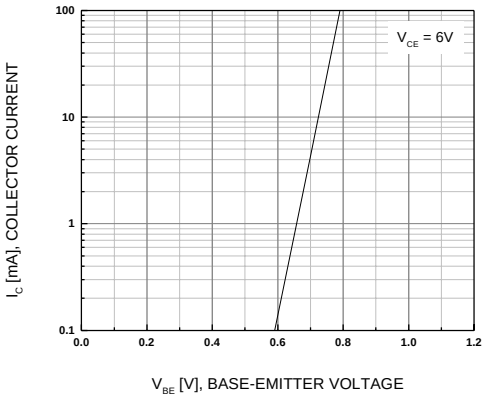


Figure 2. Base-Emitter On Voltage

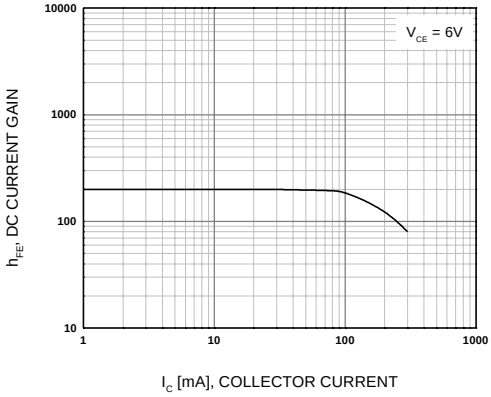


Figure 3. DC Current Gain

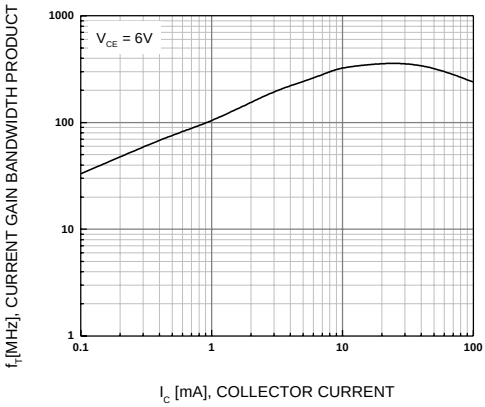


Figure 4. f_T - I_C

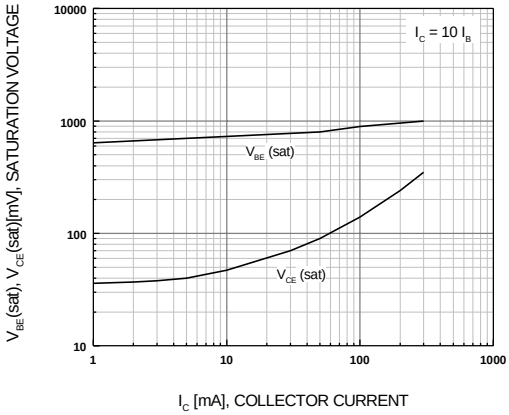


Figure 5. Saturation Voltage

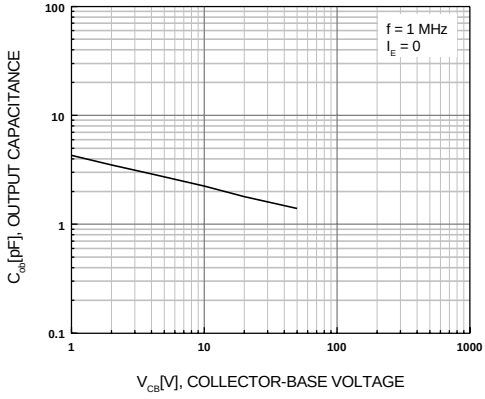
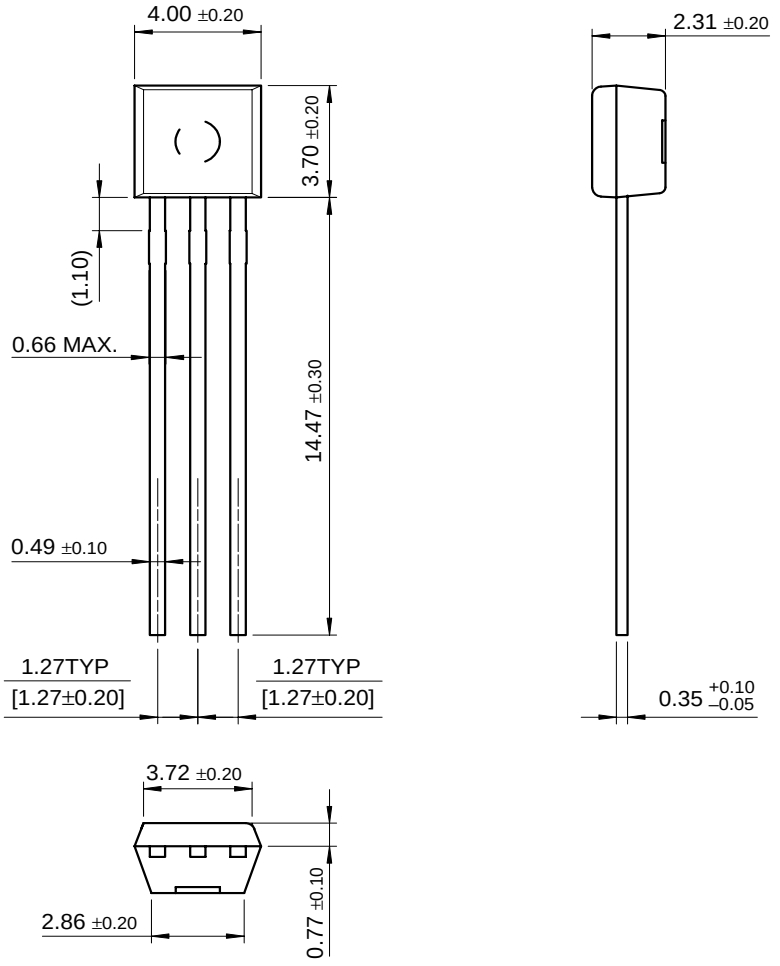


Figure 6. Output Capacitance

Package Dimensions

TO-92S



Dimensions in Millimeters

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CoolFET™	FASTr™	MicroFET™	PowerTrench®	SuperSOT™-6
CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
DOME™	GlobalOptoisolator™	MICROWIRE™	QS™	SyncFET™
EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic™
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Definition of Terms

Datasheet Identification	Product Status	Definition
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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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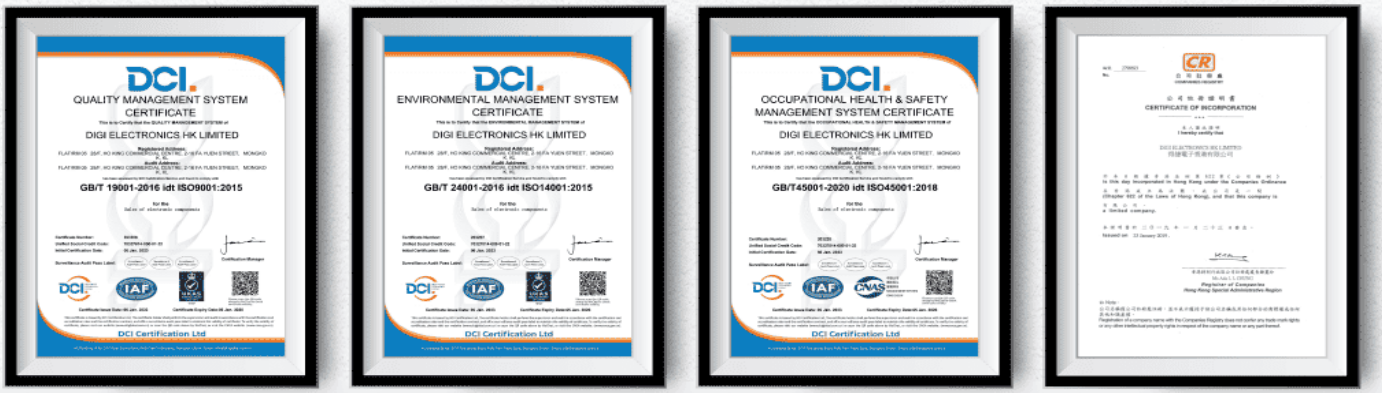

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